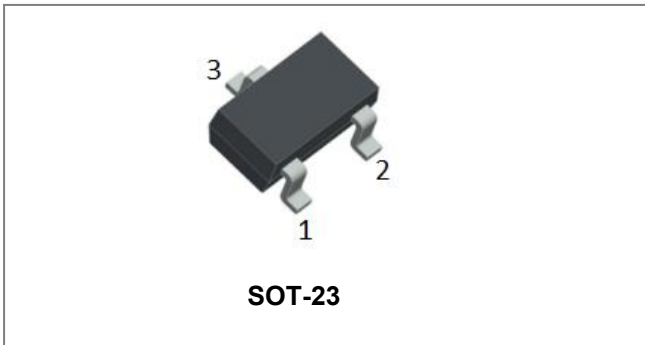


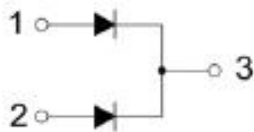
BAV70 SWITCHING DIODE



Features

- **High Conductance**
- **Fast Switching**
- **Surface Mount Package Ideally Suited for Automatic Insertion**
- **For General Purpose and Switching**
- **Plastic Material - UL Recognition Flammability Classification 94V-O**
- **This is a Pb - Free Device**
- **All SMC parts are traceable to the wafer lot**
- **Additional testing can be offered upon request**

Schematic & Pin Configuration



Mechanical Characteristics

- **Case: SOT-23, Molded Plastic**
- **Terminals: Plated leads Solderable per MIL-STD-202, Method 208**
- **Mounting Position: Any**
- **Marking: A4**

Maximum Ratings@T_A=25°C unless otherwise specified

Characteristic	Symbol	Limits	Units
Reverse Voltage	V _R	70	V
Forward Current	I _F	200	mA
Non-Repetitive Peak Forward Surge Current @t=8.3ms	I _{FSM}	2.0	A
Power Dissipation	P _D	225	mW
Typical Thermal Resistance, Junction to Ambient Air	R _{θJA}	556	°C/W
Junction and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics @T_A=25°C unless otherwise specified

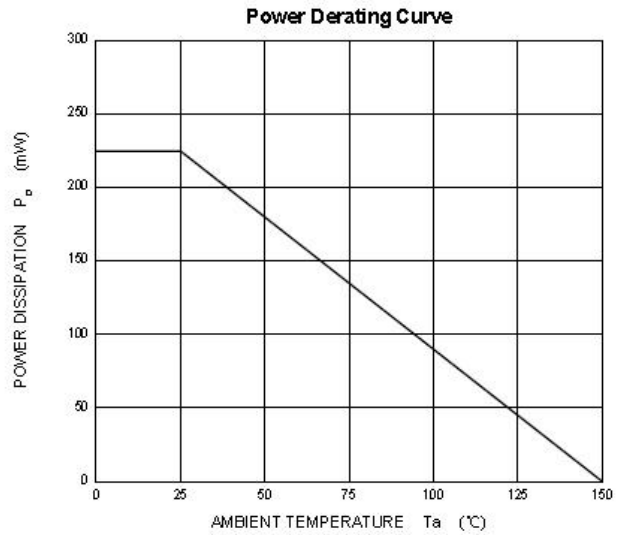
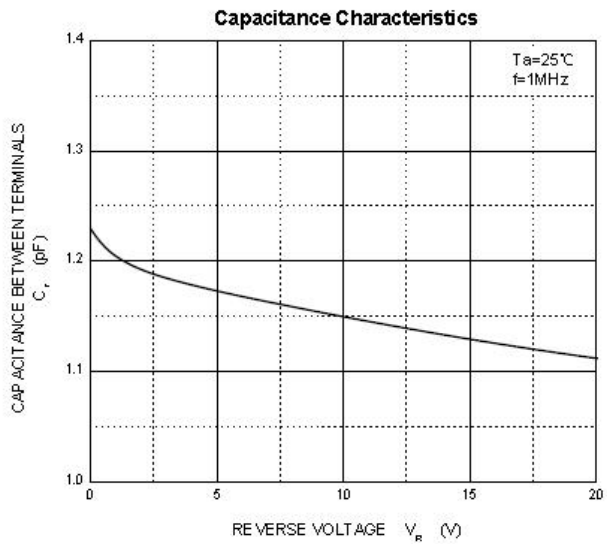
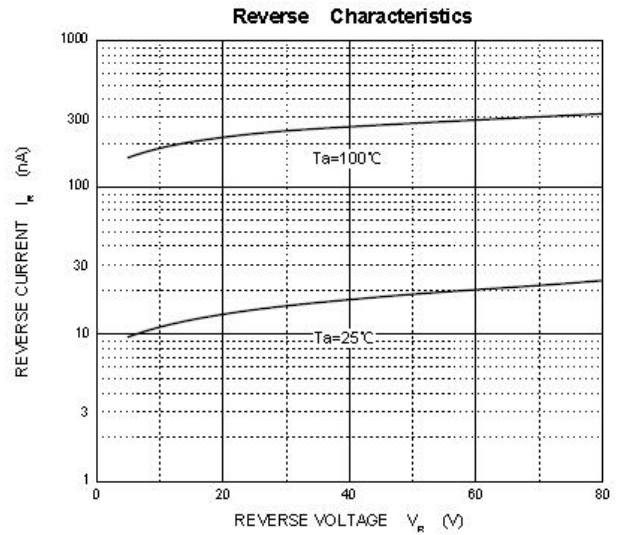
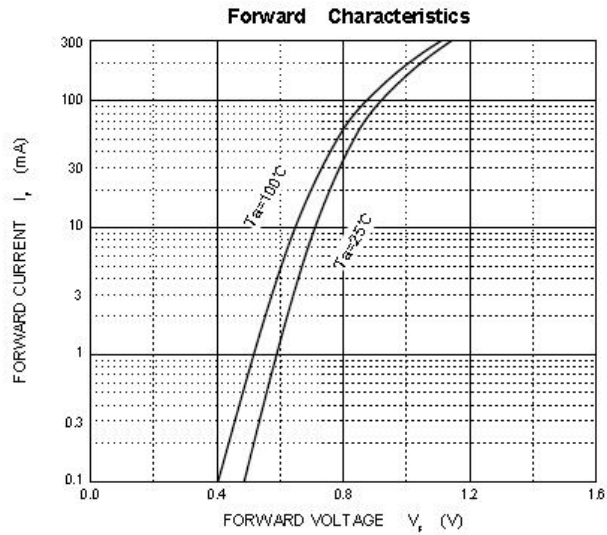
Characteristic	Symbol	Min	Max	Units	Test Condition
Reverse Breakdown Voltage*	V _{BR}	70	-	V	@I _F =100uA
Forward Voltage*	V _F	-	0.715 0.855 1 1.25	V	@I _F =1mA @I _F =10mA @I _F =50mA @I _F =150mA
Reverse Leakage Current*	I _R	-	2.5	uA	@V _R =70V
Capacitance between terminals	C _T	-	1.5	pF	V _R =0V, f=1.0MHz
Reverse Recovery Time	t _{rr}	-	6.0	ns	I _F =I _R =10mA, I _{RR} =0.1 × I _R , R _L =100Ω

* Pulse width < 300 μs, duty cycle < 2%

Note: 1. Device mounted on fiberglass substrate 40×40×1.5mm

- China - Germany - Korea - Singapore - United States •
- <http://www.smc-diodes.com> - sales@smc-diodes.com •

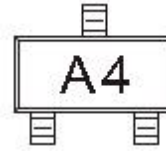
Ratings and Characteristics Curves



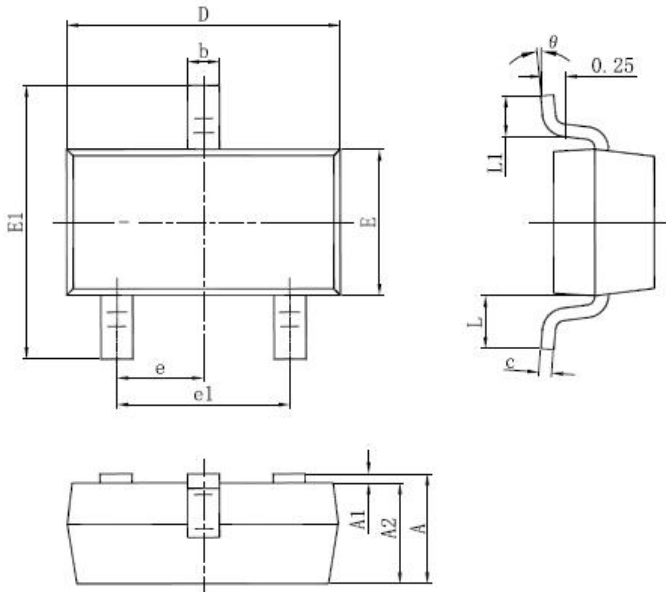
Ordering Information

Device	Package	Shipping
BAV70	SOT-23 (Pb-Free)	3000pcs / reel

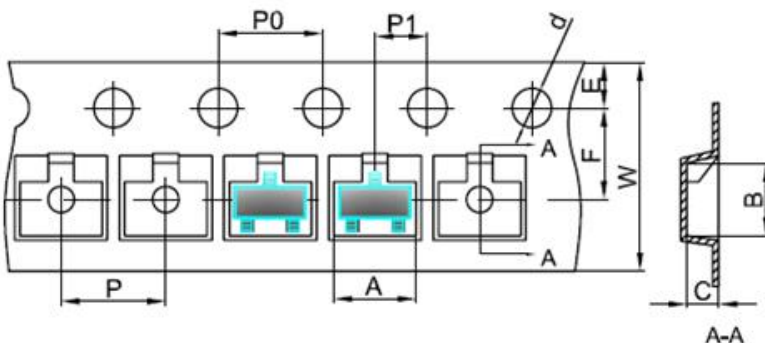
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram


A4 = Marking Code

Mechanical Dimensions SOT-23


SYMBOL	Millimeters		Inches	
	MIN.	MAX.	MIN.	MAX.
A	0.890	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.076	0.170	0.003	0.007
D	2.650	3.050	0.104	0.120
E	1.190	1.400	0.047	0.055
E1	2.100	2.550	0.083	0.100
e	0.950 TYP.		0.037 TYP.	
e1	1.780	2.050	0.070	0.081
L	0.550 REF.		0.022 REF.	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

Carrier Tape Specification SOT-23


SYMBOL	Millimeters	
	Min.	Max.
A	3.05	3.25
B	2.67	2.87
C	1.12	1.32
d	1.40	1.60
E	1.65	1.85
F	3.40	3.60
P	3.90	4.10
P0	3.90	4.10
P1	1.90	2.10
W	7.90	8.30

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